NSN 5961-01-081-5117

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-081-5117 **Inclosure Material:** Plastic **Overall Length:** 0.367 inches **Terminal Length:** 1.100 inches **End Application:** Direct access radar channel (darc)3 **Mounting Method:** Terminal **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 5.5 reverse voltage, total rms **Current Rating Per Characteristic:** 1.00 milliamperes forward current, average peak **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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